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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use many sheets as necessary)

Complete if Known

Application Number	10/695,432
Filing Date	October 28, 2003
First Named Inventor	Kan, Edwin
Group Art Unit	2812 5
Examiner Name	Unknown <i>A. Wilson</i>

Sheet 1 of 4

Attorney Docket No: 1153.078US1

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<i>Qu</i>	US-5,071,770	12/10/1991	Kolesar Jr., Edward S.	436	151	11/05/1990

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Group Art Unit 2812.5

Examiner Name Unknown *A. Wilson*

Sheet 2 of 4

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<i>Dee</i>		YAMAMOTO, T., et al., "An Integrated Temperature and Humidity Sensor", Proc. Transducers'87, Tokyo, Japan, (June 1987), 658-660	

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